

# **DATASHEET**

# 8 PIN SOP DUAL CHANNEL HIGH SPEED 10MBit/s LOGIC GATE PHOTOCOUPLER EL063X series



#### **Features**

- •Compliance Halogen Free . (Br <900 ppm ,Cl <900 ppm , Br+Cl < 1500 ppm)
- •High speed 10Mbit/s
- •10kV/µs min. common mode transient immunity (EL0631)
- Guaranteed performance from -40 to 85°C
- Wide operating temperature range of -40 °C to 100 °C
- · Logic gate output
- High isolation voltage between input and output (Viso=3750 V rms)
- Compliance with EU REACH
- Pb free and RoHS compliant
- UL and cUL approved(No. E214129)
- VDE approved (No.40028116)
- SEMKO approved
- NEMKO approved
- DEMKO approved
- FIMKO approved

# **Description**

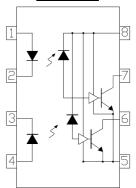
The EL0630 and EL0631 are dual channel devices each consists of an infrared emitting diode optically coupled to a high speed integrated photo detector logic gate with a strobable output.

The devices are packaged in an 8-pin small outline package which conforms to the standard SO8 footprint.

## **Applications**

- Ground loop elimination
- LSTTL to TTL, LSTTL or 5 volt CMOS
- Line receiver, data transmission
- Data multiplexing
- Switching power supplies
- Pulse transformer replacement
- Computer peripheral interface

#### **Schematic**



#### Pin Configuration

- 1. Anode
- 2. Cathode
- 3. Cathode
- 4. Anode
- 5. Gnd
- 6. Vout 2
- 7. Vout 1
- 8. V<sub>CC</sub>

### **Truth Table (Positive Logic)**

Input	Output		
Τ	L		
L	Н		



# Absolute Maximum Ratings (Ta=25℃)

	Parameter	Symbol	Rating	Unit
	DC/ Average Forward current	I <sub>F</sub>	20	mA
Input	Reverse voltage	$V_{R}$	5	V
	Power dissipation	P <sub>D</sub>	45	mW
	Power dissipation	$P_{C}$	60	mW
Output	Output current	Io	50	mA
Output	Output voltage	Vo	7.0	V
	Supply voltage (max 1 minute)	V <sub>CC</sub>	7.0	V
Output F	Output Power Dissipation		80	mW
Isolation	Isolation voltage *1		3750	V rms
Operating temperature		T <sub>OPR</sub>	-40 ~ +100	℃
Storage	Storage temperature		-55 ~ +125	℃
Solderin	g temperature *2	T <sub>SOL</sub>	260	℃

#### Notes:

<sup>\*1</sup> AC for 1 minute, R.H.=  $40 \sim 60\%$  R.H. In this test, pins 1, 2, 3, 4 are shorted together, and pins 5, 6, 7, 8 are shorted together.

<sup>\*2</sup> For 10 seconds



# Electrical Characteristics (Ta=-40 to 85 °C unless specified otherwise)

# Input

Parameter	Symbol	Min.	Тур.	Max.	Unit	Condition
Forward voltage	$V_{F}$	-	1.4	1.8	V	I <sub>F</sub> =10mA
Reverse voltage	$V_{R}$	5.0	-	-	V	I <sub>R</sub> =10μA
Temperature coefficient of forward voltage	$\Delta V_F/\Delta T_A$	-	-1.8	-	mV/℃	I <sub>F</sub> =10mA
Input capacitance	$C_{IN}$	-	60	-	pF	V <sub>F</sub> =0, f=1MHz

#### Output

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
High level supply current	I <sub>CCH</sub>	-	13	18	mA	$I_F = 0 \text{mA}, \ V_{CC} = 5.5 \text{V}$
Low level supply current	I <sub>CCL</sub>	-	15	21	mA	$I_F = 10 \text{mA}, V_{CC} = 5.5 \text{V}$

# Transfer Characteristics (Ta=-40 to 85 ℃ unless specified otherwise)

Parameter	Symbol	Min	Тур.	Max.	Unit	Condition
HIGH Level Output Current	l <sub>он</sub>	-	-	100	μΑ	$V_{CC}$ =5.5V, $V_{O}$ =5.5V, $I_{F}$ =250 $\mu$ A,
LOW Level Output Current	$V_{OL}$	-	-	0.6	V	$V_{CC}$ =5.5V, $I_F$ =5mA, $I_{CL}$ =13mA
Input Threshold Current	I <sub>FT</sub>	-	-	5	mA	$V_{CC} = 5.5V, V_O = 0.6V,$ $I_{OL} = 13mA$

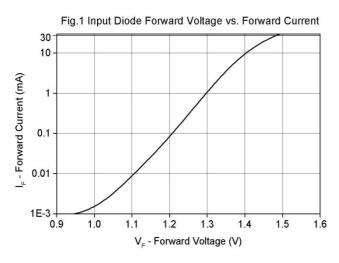


# Switching Characteristics (T<sub>a</sub>=-40 to 85 ℃, V<sub>CC</sub>=5V, I<sub>F</sub>=7.5mA unless specified otherwise)

Parameter		Symbol	Min	Тур.	Max.	Unit	Condition
			-	-	100	ns	$C_L$ =15pF, $R_L$ =350Ω, $T_A$ =25 $^{\circ}$ C
Propagation time to outp level* <sup>5</sup> (Fig.11)		t <sub>PLH</sub>	-	-	100	ns	$C_L = 15 pF, R_L = 350 \Omega,$ $T_A = 25 °C$
Pulse width		t <sub>PHL</sub> — t <sub>PLH</sub>	-	-	35	ns	$C_L = 15pF, R_L = 350\Omega$
Output rise (Fig.11)	time* <sup>6</sup>	t <sub>r</sub>	-	40	-	ns	$C_L = 15pF, R_L = 350\Omega$
Output fall t (Fig.11)	Output fall time* <sup>7</sup> (Fig.11)		-	10	-	ns	$C_L = 15 pF, R_L = 350 \Omega$
Common Mode Transient	EL0630	· ICM <sub>H</sub> I	5000			W	$I_F = 0 \text{mA} \text{ , V}_{OH(MIN)}$ =2.0V, R <sub>L</sub> =350 $\Omega$ , T <sub>A</sub> =25 °C IV <sub>CM</sub> I =1KV(Fig.12)
Immunity at Logic High* <sup>8</sup>	EL0631		10000	· -	-	V/μs	$I_F = 0$ mA $V_{OH(MIN)} = 2.0$ V, $V_{L} = 350$ $V_{L} = 25$ C $V_{CM} = 1$ KV(Fig. 12)
Common Mode Transient	EL0630				V/µs	$\begin{array}{l} I_{\text{F}}\!=\!7.5\text{mA}, V_{\text{OL(MAX)}} \\ =\!0.8\text{V}, \; R_{\text{L}}\!=\!350\Omega, \; T_{\text{A}} \\ =\!25^{\circ}\text{C} \\ IV_{\text{CM}}I =\!1\text{KV(Fig.12}) \end{array}$	
Immunity at Logic Low*9	EL0631	- ICM <sub>L</sub> I -	10000	-	-	ν/μ5	$\begin{array}{l} I_{\text{F}}\!=\!7.5\text{mA}, V_{\text{OL(MAX)}} \\ =\!0.8\text{V}, \; R_{\text{L}}\!=\!350\Omega, \; T_{\text{A}} \\ =\!25^{\circ}\!\text{C} \\ IV_{\text{CM}}I =\!1\text{KV(Fig.12}) \end{array}$



## **Typical Electro-Optical Characteristics Curves**





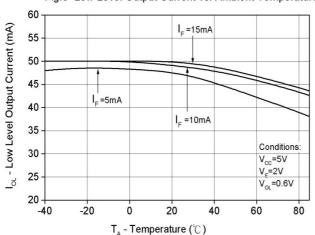


Fig.5 Output Voltage vs. Input Forward Current

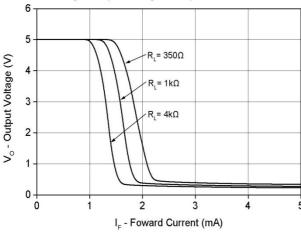


Fig.2 Low Level Output Voltage vs. Ambient Temperature

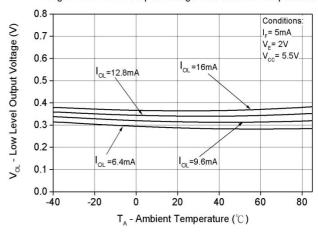


Fig.4 Input Threshold Current vs. Ambient Temperature

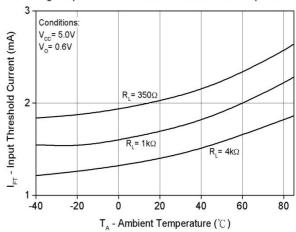
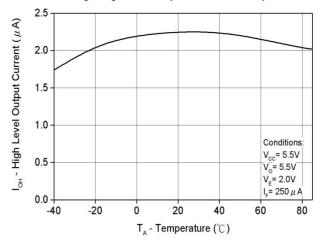
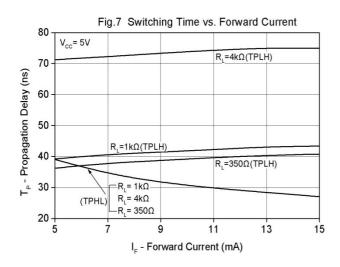
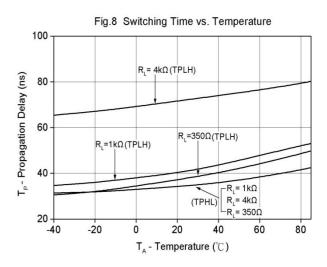
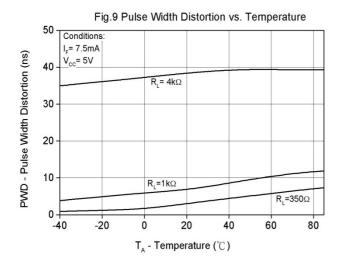


Fig.6 High Level Output Current vs. Temperature









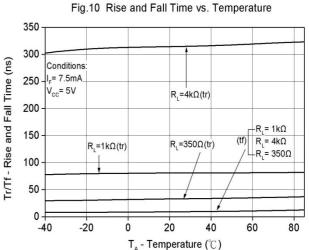


Fig. 11 Test circuit and waveforms for  $t_{\text{PHL}},\,t_{\text{PLH}},\,t_{\text{r}},$  and  $t_{\text{f}}$ 

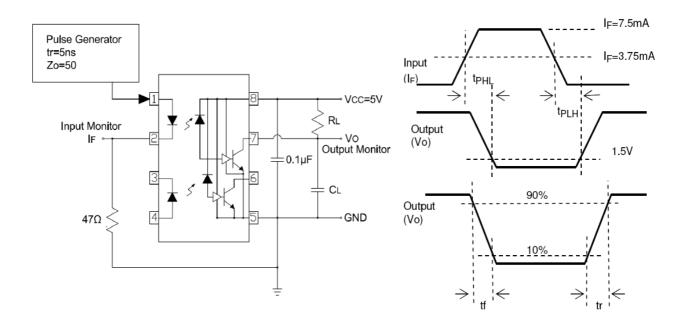
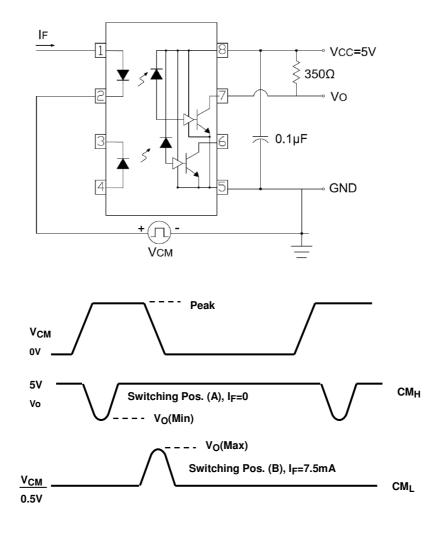


Fig. 12 Test circuit Common mode Transient Immunity





#### **Notes**

- \*3 The  $V_{CC}$  supply must be bypassed by a  $0.1\mu F$  capacitor or larger. This can be either a ceramic or solid tantalum capacitor with good high frequency characteristic and should be connected as close as possible to the package  $V_{CC}$  and GND pins
- \*4. t<sub>PLH</sub> Propagation delay is measured from the 3.75mA level on the HIGH to LOW transition of the input current pulse to the 1.5 V level on the LOW to HIGH transition of the output voltage pulse.
- \*5. t<sub>PHL</sub> Propagation delay is measured from the 3.75mA level on the LOW to HIGH transition of the input current pulse to the 1.5 V level on the HIGH to LOW transition of the output voltage pulse.
- \*6. t<sub>r</sub> Rise time is measured from the 90% to the 10% levels on the LOW to HIGH transition of the output pulse.
- \*7. t<sub>f</sub> Fall time is measured from the 10% to the 90% levels on the HIGH to LOW transition of the output pulse.
- \*8  $CM_H$  The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the HIGH state (i.e.,  $V_{OUT} > 2.0V$ ).
- \*9  $CM_L$  The maximum tolerable rate of rise of the common mode voltage to ensure the output will remain in the LOW output state (i.e.,  $V_{OUT} < 0.8V$ ).

#### **Order Information**

#### **Part Number**

# **EL063X(Z)-V**

#### Note

X = Part no. (X = 0 or 1)

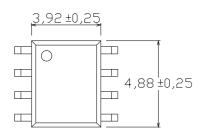
Z = Tape and reel option (TA, TB or none).

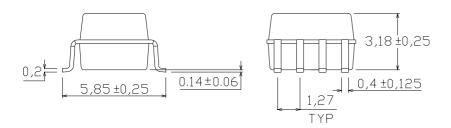
V = VDE (optional)

Option	Description	Packing quantity		
None	Standard	100 units per tube		
-V	Standard + VDE	100 units per tube		
(TA)	TA tape & reel option	2000 units per reel		
(TB)	TB tape & reel option	2000 units per reel		
(TA)-V	TA tape & reel option + VDE	2000 units per reel		
(TB)-V	TB tape & reel option + VDE	2000 units per reel		

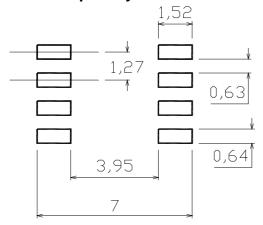


# Package Dimension (Dimensions in mm)



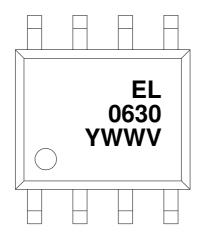


# Recommended pad layout for surface mount leadform





# **Device Marking**

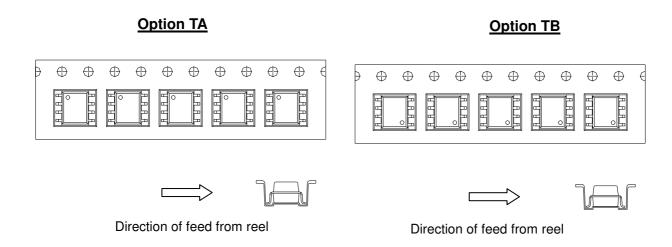


#### Notes

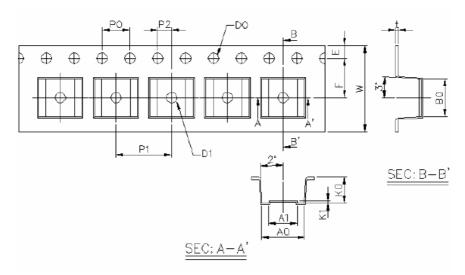
0630 denotes Device Number
Y denotes 1 digit Year code
WW denotes 2 digit Week code
V denotes VDE (optional)



**Tape & Reel Packing Specifications** 



# **Tape dimensions**



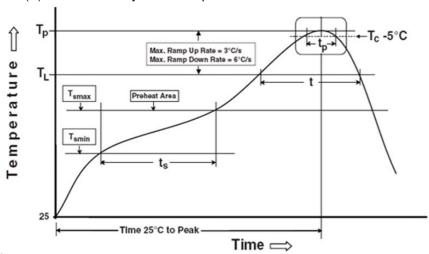
Dimension No.	Α0	<b>A</b> 1	В0	D0	D1	E	F
Dimension(mm)	6.2±0.1	4.1±0.1	5.28±0.1	1.5±0.1	1.5±0.3	1.75±0.1	5.5±0.1
Dimension No.	Po	P1	P2	t	W	K0	K1
Dimension(mm)	4.0±0.1	8.0±0.1	2.0±0.1	0.4±0.1	12.0+0.3/ -0.1	3.7±0.1	0.3±0.1



#### **Precautions for Use**

#### 1. Soldering Condition

1.1 (A) Maximum Body Case Temperature Profile for evaluation of Reflow Profile



Note: Reference: IPC/JEDEC J-STD-020D

#### **Preheat**

Temperature min ( $T_{smin}$ )

150 °C

Temperature max ( $T_{smax}$ )

200 °C

Time ( $T_{smin}$  to  $T_{smax}$ ) ( $t_s$ )

60-120 seconds

Average ramp-up rate ( $T_{smax}$  to  $T_p$ )

3 °C/second max

#### Other

Liquidus Temperature ( $T_L$ ) 217 °C Time above Liquidus Temperature ( $t_L$ ) 60-100 sec Peak Temperature ( $T_P$ ) 260 °C Time within 5 °C of Actual Peak Temperature:  $T_P$  - 5 °C 30 s Ramp- Down Rate from Peak Temperature 6 °C /second max.

Time 25 ℃ to peak temperature 8 minutes max.

Reflow times 3 times



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